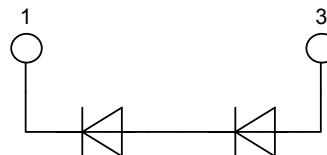


**HiPerDynFRED**

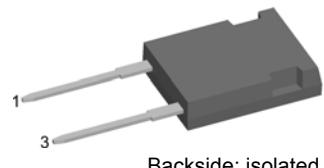
High Performance Dynamic Fast Recovery Diode  
Extreme Low Loss and Soft Recovery  
Single Diode

Part number

DSEP30-12CR



**V<sub>RRM</sub>** = 1200 V  
**I<sub>FAV</sub>** = 30 A  
**t<sub>rr</sub>** = 15 ns



Backside: isolated

E72873

**Features / Advantages:**

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I<sub>rm</sub>-values
- Very soft recovery behaviour
- Soft reverse recovery for low EMI/RFI
- Low I<sub>rm</sub> reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

**Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

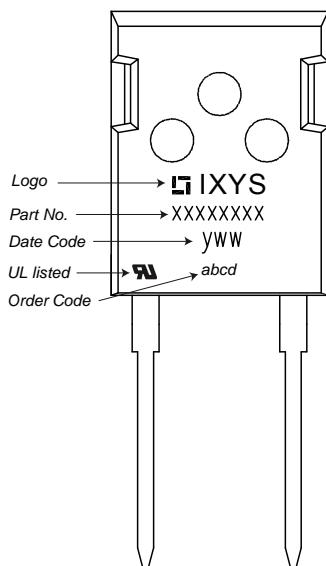
**Package:**

- Housing: ISOPLUS247
- Industry standard outline
- DCB isolated backside
- Isolation Voltage 3000 V
- Epoxy meets UL 94V-0
- RoHS compliant

Symbol	Definition	Conditions		Ratings		
		min.	typ.	max.	Unit	
V <sub>RRM</sub>	max. repetitive reverse voltage			1200		V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1200 V	T <sub>VJ</sub> = 25 °C		250	µA
		V <sub>R</sub> = 1200 V	T <sub>VJ</sub> = 150 °C		2	mA
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 30 A	T <sub>VJ</sub> = 25 °C		4.98	V
		I <sub>F</sub> = 60 A			6.33	V
		I <sub>F</sub> = 30 A	T <sub>VJ</sub> = 150 °C		3.18	V
		I <sub>F</sub> = 60 A			4.40	V
I <sub>FAV</sub>	average forward current	rectangular d = 0.5	T <sub>C</sub> = 120 °C		30	A
V <sub>F0</sub>	threshold voltage	} slope resistance for power loss calculation only	T <sub>VJ</sub> = 175 °C		1.42	V
r <sub>F</sub>	slope resistance				24.4	mΩ
R <sub>thJC</sub>	thermal resistance junction to case				0.60	K/W
T <sub>VJ</sub>	virtual junction temperature			-55	175	°C
P <sub>tot</sub>	total power dissipation		T <sub>C</sub> = 25 °C		250	W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms (50 Hz), sine	T <sub>VJ</sub> = 45 °C		250	A
I <sub>RM</sub>	max. reverse recovery current		T <sub>VJ</sub> = 25 °C		5.5	A
		I <sub>F</sub> = 30 A; V <sub>R</sub> = 600 V	T <sub>VJ</sub> = 100 °C		12.5	A
t <sub>rr</sub>	reverse recovery time	-di <sub>F</sub> /dt = 600 A/µs	T <sub>VJ</sub> = 25 °C		15	ns
			T <sub>VJ</sub> = 100 °C		70	ns
C <sub>J</sub>	junction capacitance	V <sub>R</sub> = 800 V; f = 1 MHz	T <sub>VJ</sub> = 25 °C		13	pF

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$I_{RMS}$	RMS current	per terminal			70	A
$R_{thCH}$	thermal resistance case to heatsink			0.25		K/W
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				6		g
$F_c$	mounting force with clip		20		120	N
$V_{ISOL}$	isolation voltage	t = 1 second t = 1 minute	3600 3000			V
$d_{Spp/App}$	creepage   striking distance on surface   through air	terminal to terminal	5.5			mm
$d_{Spb/Abp}$	creepage   striking distance on surface   through air	terminal to backside	5.5			mm

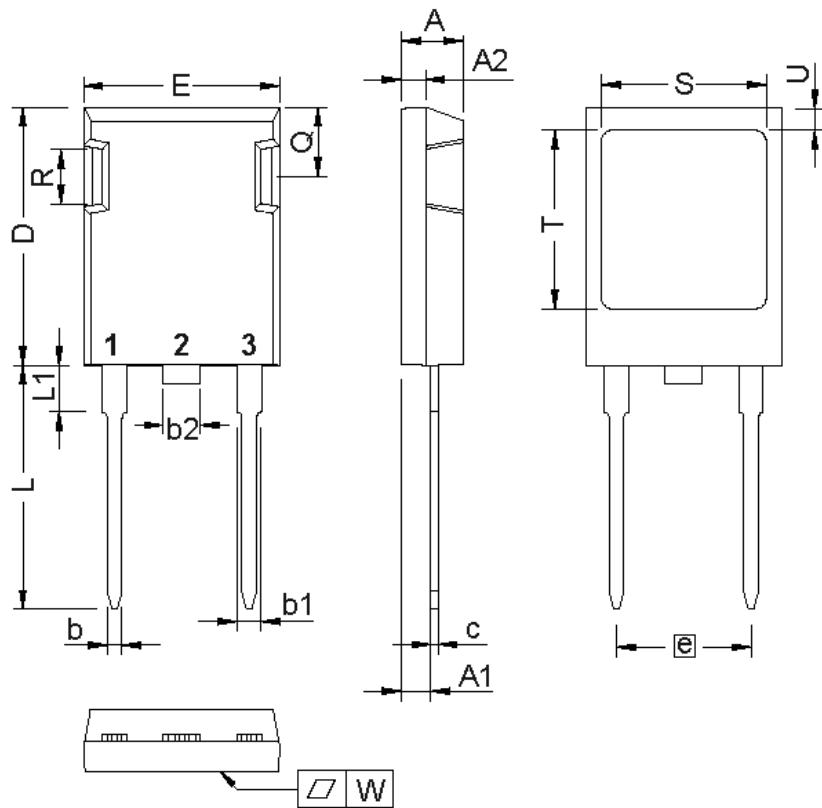
### Product Marking



Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSEP30-12CR	DSEP30-12CR	Tube	30	481955

Similar Part	Package	Voltage Class
DSEP30-12A	TO-247AD (2)	1200
DSEP29-12A	TO-220AC (2)	1200
DSEP30-12AR	ISOPLUS247 (2)	1200
DHG301200HA	TO-247AD (2)	1200

## Outlines ISOPLUS247



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.83	5.21	0.190	0.205
A1	2.29	2.54	0.090	0.100
A2	1.91	2.16	0.075	0.085
b	1.14	1.40	0.045	0.055
b1	1.91	2.15	0.075	0.085
b2	2.92	3.20	0.115	0.126
c	0.61	0.83	0.024	0.033
D	20.80	21.34	0.819	0.840
E	15.75	16.13	0.620	0.635
e	10.90 BSC		0.430 BSC	
L	19.81	20.60	0.780	0.811
L1	3.81	4.38	0.150	0.172
L2	0.00	2.54	0.000	0.100
Q	5.59	6.20	0.220	0.244
R	4.32	4.85	0.170	0.191
S	13.21	13.72	0.520	0.540
T	15.75	16.26	0.620	0.640
U	1.65	2.03	0.065	0.080
W	-	0.10	-	0.004

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite.  
The convex bow of substrate is typ. < 0.04 mm over plastic surface level of device bottom side.

Die Gehäuseabmessungen entsprechen dem Typ TO-247 AD gemäß JEDEC außer Schraubloch und  $L_{max}$ .  
This drawing will meet all dimensions requirement of JEDEC outline TO-247 AD except screw hole and except  $L_{max}$ .

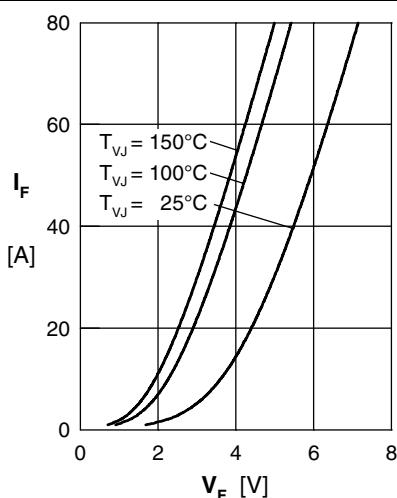
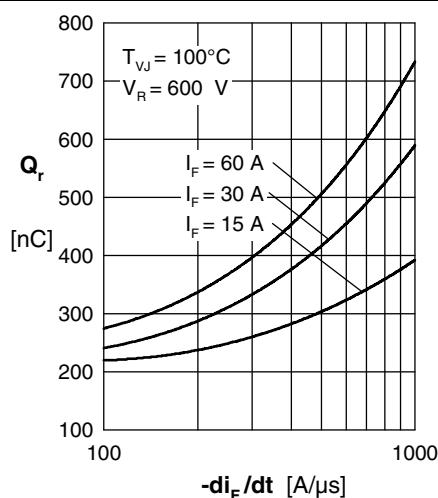
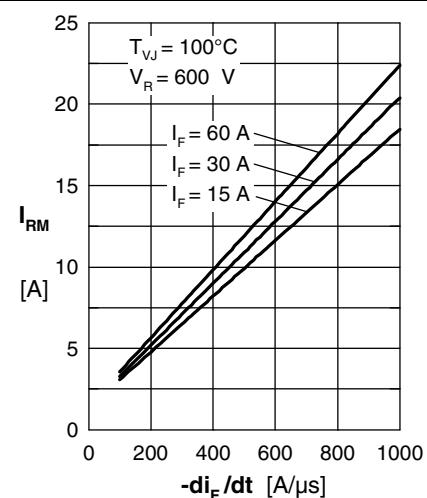
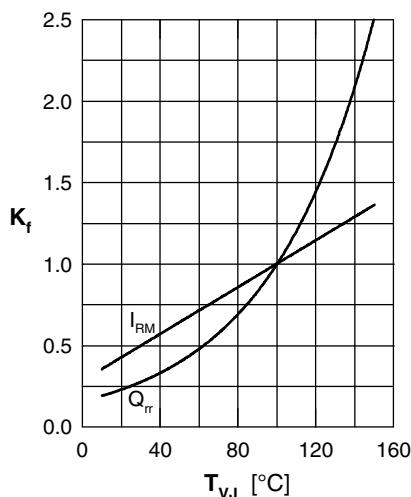
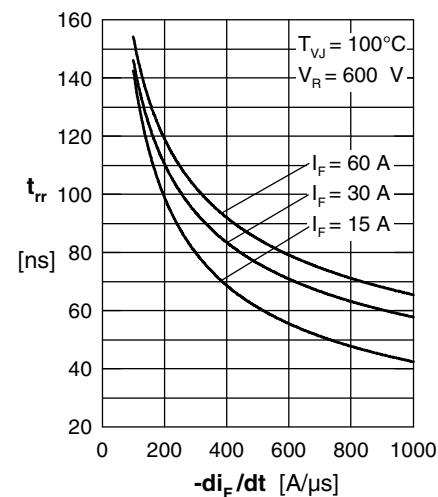
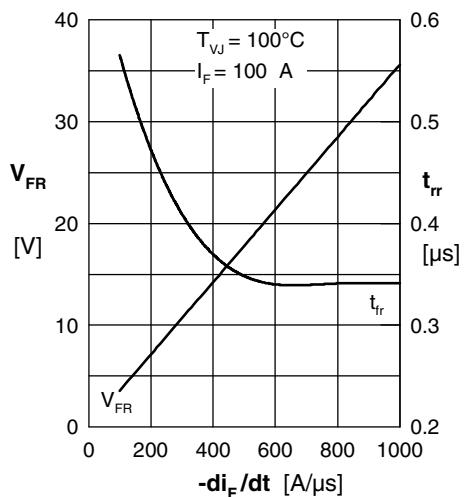
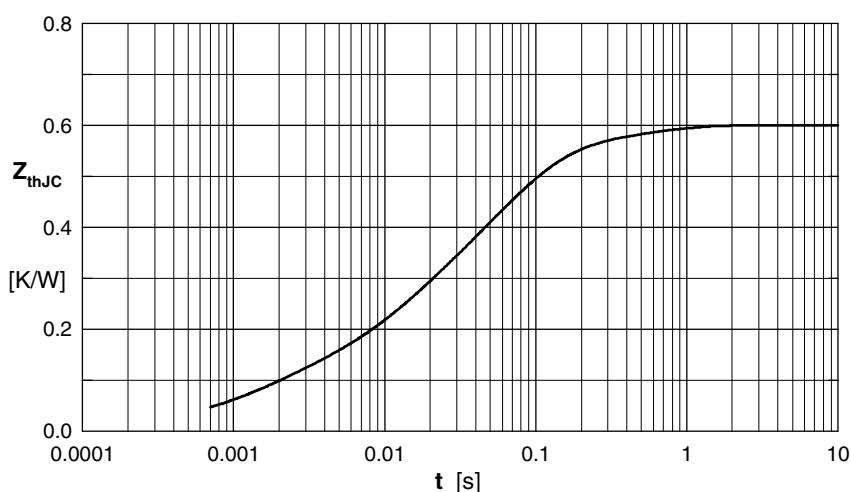
Fig. 1 Forward current  $I_F$  vs.  $V_F$ Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$ Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$ Fig. 4 Dynamic parameters  $Q_{rr}$ ,  $I_{RM}$  versus  $T_{VJ}$ Fig. 5 Recovery time  $t_{rr}$  versus  $-di_F/dt$ Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$ 

Fig. 7 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.08	0.0013
2	0.122	0.0097
3	0.116	0.037
4	0.23	0.07
5	0.052	0.45